# Silicon Carbide Schottky Diode

650 V, 20 A

# FFSD2065B

Silicon Carbide (SiC) Schottky Diodes use a completely new technology that provides superior switching performance and higher reliability compared to Silicon. No reverse recovery current, temperature independent switching characteristics, and excellent thermal performance sets Silicon Carbide as the next generation of power semiconductor. System benefits include highest efficiency, faster operating frequency, increased power density, reduced EMI, and reduced system size and cost.

#### Features

- Max Junction Temperature 175°C
- Avalanche Rated 94 mJ
- High Surge Current Capacity
- Positive Temperature Coefficient
- Ease of Paralleling
- No Reverse Recovery/No Forward Recovery
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

#### Applications

- General Purpose
- SMPS, Solar Inverter, UPS
- Power Switching Circuit

### **ABSOLUTE MAXIMUM RATINGS**

(T <sub>C</sub> = 25°C,	Unless otherwise	specified)
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Symbol	Para	Value	Unit	
V <sub>RRM</sub>	Peak Repetitive Rev	650	V	
E <sub>AS</sub>	Single Pulse Avalan	94	mJ	
١ <sub>F</sub>	Continuous Rectified Forward Current @ $T_C < 143^{\circ}C$		20	A
	Continuous Rectified @ $T_C < 135^{\circ}C$	23.4		
I <sub>F, Max</sub>	Non-Repetitive Peak Forward	$T_C = 25^{\circ}C$ , 10 µs	763	А
	Surge Current	$T_{C} = 150^{\circ}C, 10 \ \mu s$	650	
I <sub>F, SM</sub>	Non-Repetitive Forward Surge Current	Half–Sine Pulse, t <sub>p</sub> = 8.3 ms	80	A
P <sub>tot</sub>	Power Dissipation	$T_{C} = 25^{\circ}C$	160	W
		T <sub>C</sub> = 150°C	27	
T <sub>J</sub> , T <sub>STG</sub>	Operating and Storage Temperature Range		–55 to +175	°C

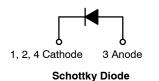
Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1.  $E_{AS}$  of 94 mJ is based on starting  $T_J = 25^{\circ}$ C, L = 0.5 mH,  $I_{AS} = 19.4$  A, V = 50 V.



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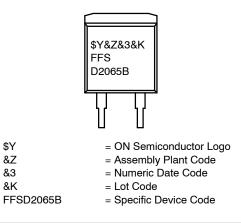
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DPAK3 (TO-252, 3 LD) CASE 369AS





### **ORDERING INFORMATION**

See detailed ordering and shipping information in the package dimensions section on page 2 of this data sheet.

## FFSD2065B

#### THERMAL CHARACTERISTICS

Symbol	Parameter	Ratings	Unit
$R_{\theta JC}$	Thermal Resistance, Junction to Case, Max.	0.94	°C/W

#### PACKAGE MARKING AND ORDERING INFORMATION

Part Number	Top Marking	Package	Shipping <sup>†</sup>
FFSD2065B	FFSD2065B	DPAK3 (Pb–Free / Halogen Free)	2500 / Tape & Reel

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D

#### **ELECTRICAL CHARACTERISTICS** $T_C = 25^{\circ}C$ unless otherwise noted

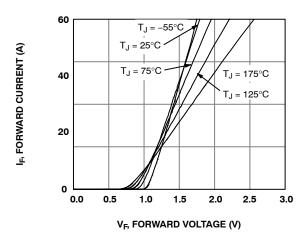
Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
V <sub>F</sub>	Forward Voltage	$I_{\rm F}$ = 20 A, $T_{\rm C}$ = 25°C		1.38	1.7	V
		$I_F = 20 \text{ A}, \text{ T}_C = 125^{\circ}\text{C}$		1.6	2.0	
		$I_F = 20 \text{ A}, \text{ T}_C = 175^{\circ}\text{C}$		1.72	2.4	
I <sub>R</sub>	Reverse Current	$V_{R} = 650 \text{ V}, \text{ T}_{C} = 25^{\circ}\text{C}$		0.5	40	μA
		$V_{R} = 650 \text{ V}, \text{ T}_{C} = 125^{\circ}\text{C}$		1	80	
		$V_{R} = 650 \text{ V}, \text{ T}_{C} = 175^{\circ}\text{C}$		2	160	
Q <sub>C</sub>	Total Capacitive Charge	V = 400 V		51		nC
С	Total Capacitance	V <sub>R</sub> = 1 V, f = 100 kHz		866		pF
		V <sub>R</sub> = 200 V, f = 100 kHz		80		
		V <sub>R</sub> = 400 V, f = 100 kHz		70		

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

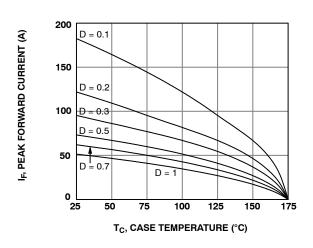
## FFSD2065B

#### **TYPICAL CHARACTERISTICS**

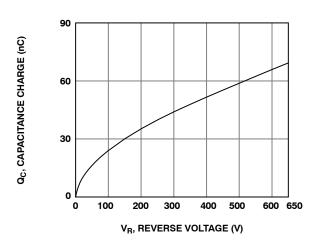
(T<sub>J</sub> = 25°C Unless Otherwise Noted)













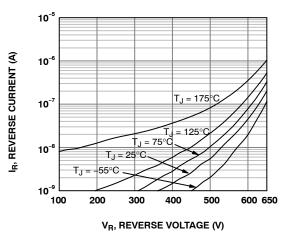


Figure 2. Reverse Characteristics

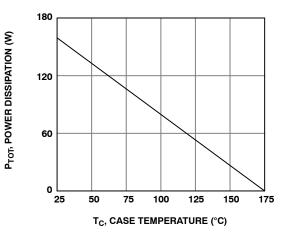


Figure 4. Power Dissipation

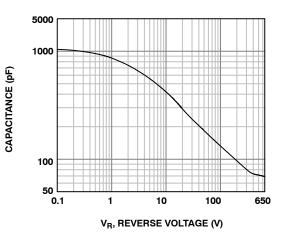


Figure 6. Capacitance vs. Reverse Voltage

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#### TYPICAL CHARACTERISTICS (continued)

(T<sub>J</sub> = 25°C Unless Otherwise Noted)

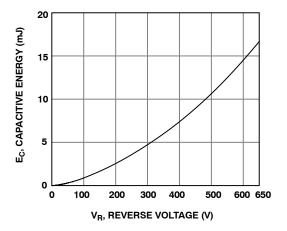
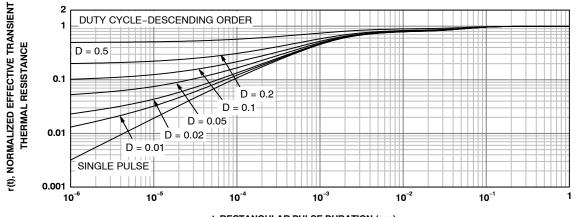


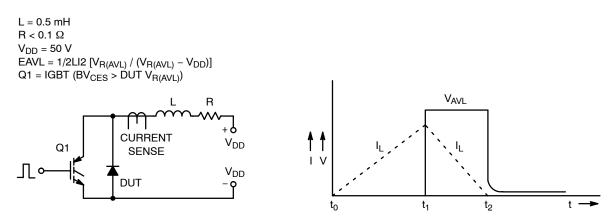
Figure 7. Capacitance Stored Energy



t, RECTANGULAR PULSE DURATION (sec)

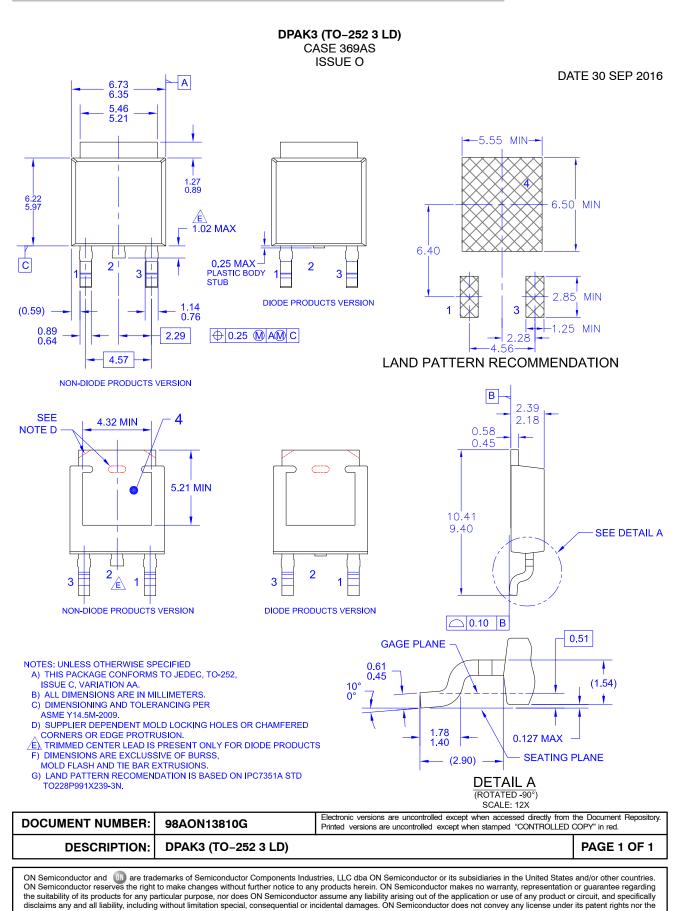
Figure 8. Junction-to-Case Transient Thermal Response Curve

#### **TEST CIRCUIT AND WAVEFORMS**









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